

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	4501	"liquid crystal display" and "tft array" and substrate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/24 10:31
S2	2979	S1 and (@ad<="20030829" or @rlad<="20030829")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 11:54
S3	3	((("6599582") or ("20030003231")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/01/21 19:07
S4	3	("9939373").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/01/21 19:14
S5	39	S2 and "ink-jet printing"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/21 19:15
S6	4508	"liquid crystal display" and "tft array" and substrate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/24 10:30
S7	2982	S6 and (@ad<="20030829" or @rlad<="20030829")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/24 10:32
S8	1	S7 and "anti-diffusion layer"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/24 10:31

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S9	40	S7 and "ink-jet printing"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/24 10:31
S10	0	S9 and "anti-diffusion layer"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/24 10:31
S11	10	"liquid crystal display" and ("anti-diffusion layer" or (anti adj diffusion adj layer))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/24 10:42
S12	9	S11 and (@ad<="20030829" or @rlad<="20030829")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/24 10:43
S13	5	(tft or "thin film transistor" or (thin adj film adj transistor)) and ("anti-diffusion layer" or (anti adj diffusion adj layer))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 11:46
S14	3	S13 and (@ad<="20030829" or @rlad<="20030829")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/24 10:43
S15	1979	"ohmic contact" and (ti or titanium) and tft and source and drain and electrode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/24 18:41
S16	1257	S15 and (@ad<="20030829" or @rlad<="20030829")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/24 18:39

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S17	2624	("ohmic contact" with (ti or titanium))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/24 18:42
S18	237	S16 and ("ohmic contact" with (ti or titanium))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/24 18:42
S19	50957	(tft or "thin film transistor" or (thin adj film adj transistor)) and ((Mo W Ag Cr Ta Ti "indium tin oxide" titanium chromium tantalum tungsten molybdenum) and (al aluminum))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 11:50
S20	1	S19 and ((source and drain) with (aluminum))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 11:52
S21	51532	(tft or "thin film transistor" or (thin adj film adj transistor)) and ((Mo W Ag Cr Ta Ti "indium tin oxide" titanium chromium tantalum tungsten molybdenum) and (aluminum))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 12:03
S22	1	S21 and ((source and drain) with (aluminum))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 11:53
S23	5133	S21 and ((source and drain) with (aluminum))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 11:53
S25	4204	S23 and (@ad<="20030829" or @rld<="20030829")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 11:54

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S26	1041	S24 and (@ad<="20030829" or @rlad<="20030829")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/25 11:54
S27	4	((("6166414") or ("6448612") or ("6608353")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/01/25 12:05